Vishay Siliconix

Automotive P-Channel 60 V (D-S) 175 °C MOSFET

PowerPAK® 1212-8W Single D D D B T Top View Bottom View

Marking code: Q057

PRODUCT SUMMARY	
V _{DS} (V)	-60
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.065
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.090
I _D (A)	-16
Configuration	Single
Package	PowerPAK 1212-8W

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

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D D P-Channel MOSFET

DADAMETED		0)/14001	1 15417		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	-60	V	
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current	T _C = 25 °C ^a		-16		
	T _C = 125 °C	ID	-11.5		
Continuous source current (diode conduction) a		I _S	-16	А	
Pulsed drain current ^b		I _{DM}	-64		
Single pulse avalanche current	1 0.1 ml l	I _{AS}	-23		
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	26	mJ	
Mayimum navay discination	T _C = 25 °C	- P _D	53	W	
Maximum power dissipation	T _C = 125 °C		17		
Operating junction and storage temperature range		T _J , T _{stq}	-55 to +175	00	
Soldering recommendations (peak temperature) d			260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB Mount c	R_{thJA}	81	°C/W
Junction-to-case (drain)		R_{thJC}	2.8	- C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300 \, \mu s$, duty cycle $\leq 2 \, \%$
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static							l
Drain-source breakdown voltage	V _{DS}	V _{GS} =	: 0 V, I _D = -250 μA	-60	-	-	.,
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
-		V _{GS} = 0 V	V _{DS} = -60 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -60 V, T _J = 125 °C	-	-	-50	μΑ
	200	V _{GS} = 0 V	V _{DS} = -60 V, T _J = 175 °C	-	-	-150	1
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≤ -5 V	-15	-	-	Α
	5(0.1)	V _{GS} = -10 V	I _D = -5.7 A	-	0.049	0.065	
	R _{DS(on)}	V _{GS} = -10 V	I _D = -5.7 A, T _J = 125 °C	-	_	0.110	
Drain-source on-state resistance a	1 1DS(on)	V _{GS} = -10 V	I _D = -5.7 A, T _J = 175 °C	-	-	0.136	Ω
		-		-	0.069	0.090	
Forward transconductance b	Ofe			-	13	-	S
Dynamic ^b	0.0		, 5				
Input capacitance	C _{iss}			-	1083	1385	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = -25 V, f = 1 MHz	-	132	165	pF
Reverse transfer capacitance	C _{rss}			-	80	105	
Total gate charge ^c	Q _a			-	25.5	38	
Gate-source charge ^c	Q _{qs}	V _{GS} = -10 V	$V_{DS} = -30 \text{ V}, I_{D} = -5.7 \text{ A}$	-	4.3	-	nC
Gate-drain charge c	Q _{ad}			-	6.4	-	
Gate resistance	R _a		f = 1 MHz	3.0	5.6	8.3	Ω
Turn-on delay time ^c				-	9	14	
Rise time ^c	t _r	Von -	30 V R: - 30 O	-	5	10	
Turn-off delay time ^c	t _{d(off)}	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	60	ns			
Fall time ^c		_		-	8	12	
Source-drain diode ratings and character	ristics ^b						
Pulsed current a	I _{SM}			-	_	-64	Α
Forward voltage	V _{SD}	l _F =	-6 A, V _{GS} = 0 V	-	-0.85	-1.2	V
Body diode reverse recovery time	t _{rr}			-	26	52	ns
Body diode reverse recovery charge	Q_{rr}	- I _F = -2 A, di/dt = 100A/μs		-	35	70	nC
Reverse recovery fall time	ta	I _F = -2	, , ω, ωι – 100/7/μ3	-	21	-	ns
Reverse recovery rise time	t _b			-	5	-	110
Body diode peak reverse recovery current	I _{RM(REC)}			-	-3.2	-	Α

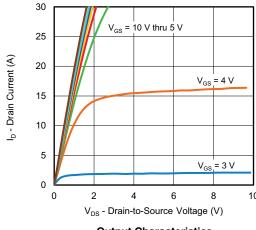
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

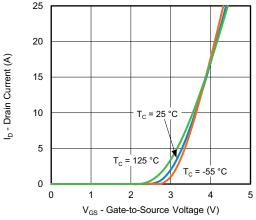
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



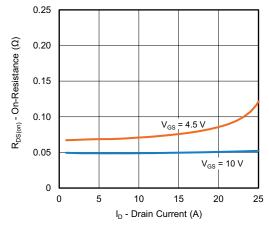
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



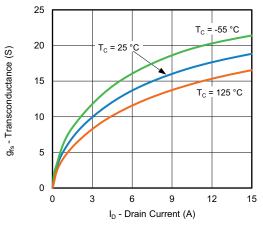




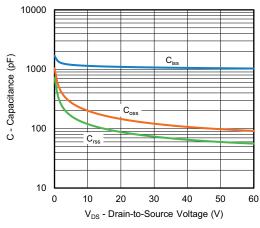
Transfer Characteristics



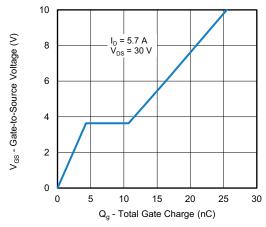
On-Resistance vs. Drain Current



Transconductance



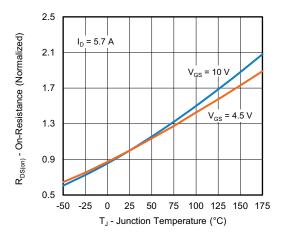
Capacitance



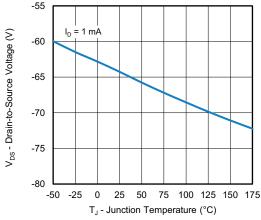
Gate Charge



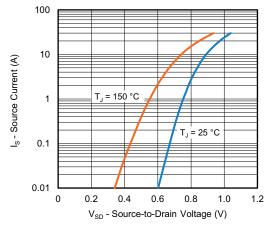
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



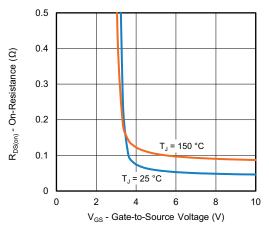
On-Resistance vs. Junction Temperature



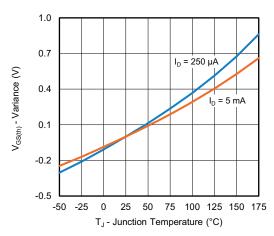
Drain Source Breakdown vs. Junction Temperature



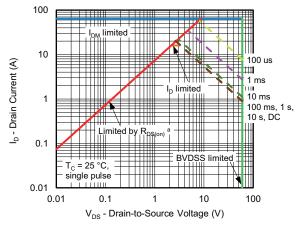
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



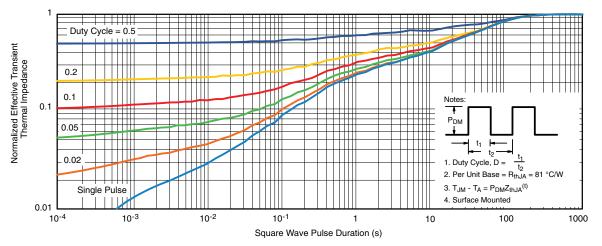
Safe Operating Area

Note

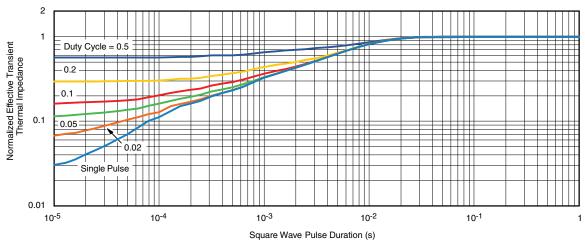
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

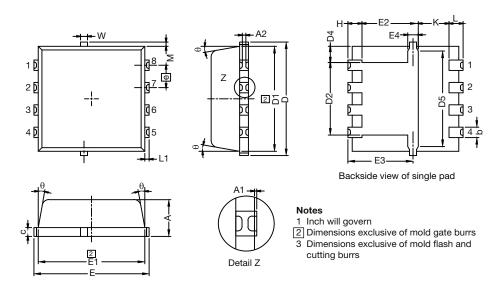
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63050.



PowerPAK® 1212-8W Case Outline



DIM.	MILLIMETERS			INCHES			
DINI.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.97	1.04	1.12	0.038	0.041	0.044	
A1	0	-	0.05	0	-	0.002	
A2	0	-	0.13	0	-	0.005	
b	0.23	0.30	0.41	0.009	0.012	0.016	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	3.20	3.30	3.40	0.126	0.130	0.134	
D1	2.95	3.05	3.15	0.116	0.120	0.124	
D2	1.98	2.11	2.24	0.078	0.083	0.088	
D4		0.47 typ.			0.0185 typ.		
D5		2.3 typ.			0.090 typ.		
Е	3.20	3.30	3.40	0.126	0.130	0.134	
E1	2.95	3.05	3.15	0.116	0.120	0.124	
E2	1.47	1.60	1.73	0.058	0.063	0.068	
E3	1.75	1.85	1.98	0.069	0.073	0.078	
E4		0.34 typ.			0.013 typ.		
е		0.65 BSC.		0.026 BSC			
K		0.86 typ.		0.034 typ.			
Н	0.30	0.41	0.51	0.012	0.016	0.020	
L	0.30	0.43	0.56	0.012	0.017	0.022	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
М	0.125 typ.			0.005 typ.			

DWG: 6032



RECOMMENDED MINIMUM PADS FOR PowerPAK® 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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